NSN 5961-00-008-7000

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-008-7000 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.352 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-77 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-emitter, base open all transistor and 6.0 breakdown voltage, emitter-to-base, collector open all transistor **Current Rating Per Characteristic:** 2.00 nanoamperes zero-gate-voltage source current preset all transistor **Power Rating Per Characteristic:** 400.0 watts large-signal input power, common-emitter preset all transistor **Transfer Ratio:** 900.0 static forward current transfer ratio, common-emitter all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: